

Adjustable Overvoltage Protection Switch

Features

- Wide Input voltage range: 2.5V to 40V
- Up to 4.5A current capability
- Integrated 26mΩ (typ) N-Channel MOSFET
- Fast OVP turn-off response time: 100ns
- Selectable trip-point options
 - ► Fixed 5.95V
 - ► Fixed 10.2V
 - ► Fixed 13.5V
- ► Adj. 4V to 28V
- Auto-enabled switch with 18ms debounce time
- Under voltage (UVLO), Short-circuit and thermal shutdown protection
- VDET output to indicate the presence of VBUS
- ESD Protection
- ► Human Body Model: ±2.0kV
- Pb-free WLCSP-12 package
- -40°C to +85°C Temperature Range

Applications

- Smartphones
- Mobile Internet Devices
- Tablet Computers
- Peripherals

Brief Description

The KTS1662 overvoltage protection device features an ultra-low $26m\Omega$ (typical) on-resistance high current integrated MOSFET which actively protects low-voltage systems from voltage supply faults up to +40V.

An input voltage exceeding the overvoltage threshold will cause the internal MOSFET to turn off, preventing excessive voltage from damaging downstream devices.

The KTS1662 offers three different fixed OVP options, plus a fully adjustable option. When the OVLO input is connected to GND, the KTS1662 automatically chooses the internal fixed OVLO threshold, preset to 5.95V (typical). Allowing OVLO to float, gives a preset of 10.2V (typical) and connecting a resistor to GND between $30k\Omega$ and $80k\Omega$ gives a preset of 13.5V (typical) The overvoltage protection threshold can also be fully adjusted with an optional external resistor divider to a voltage between 4V and 28V.

The KTS1662 features a VDET output to indicate the presence of a voltage at VBUS and is independent of the OVP switch. In case the device temperature exceeds the maximum junction temperature, the device switches off.

The KTS1662 is available in a RoHS and Green compliant 12-Bump 1.28 x 1.94 x 0.062mm WLCSP.

Typical Application





Pin Descriptions

Pin #	Name	Function
A1	ĒN	OUT power path is Enabled when \overline{EN} is logic Low.
A2, A3, B2	OUT	Power switch output pin
B1	VDET	Output from IN pin, with internal protection clamp. VDET can source 1mA
A4, B4, C4	GND	Ground. For correct operation, connect all GND pins to GND
C1	OVLO	External OVLO adjustment. See Table 1
B3, C2, C3	IN	Power switch input pin. Bypass IN with $0.1\mu F$ capacitor as close as possible to the device.

WLCSP-12



12-Bump 1.28mm x 1.94mm x 0.62mm

WLCSP Package

Top Mark WW = Device ID Code = KV XX = Date Code, YY = Assembly Code

Table 1. OVP Selection

OVLO Pin	OVP Voltage
GND	5.95V
FLOAT	10.2V
30kΩ to 80kΩ to GND	13.5V
Resistive divider from VIN to GND	Adjustable

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Absolute Maximum Ratings¹

Symbol	Description	Value	Units
IN	Input voltage	-0.3 to 42	V
OUT	Output voltage	-0.3 to VIN+0.3	V
OVLO	OVLO Pin	-0.3 to 12	V
VDET, EN	EN, VDET Pins	-0.3 to 7	V
IN, OUT Current	Continuous Current	4.5	А
TJ	Operating Temperature Range	-40 to 150	°C
Ts	Storage Temperature Range	-65 to 150	°C
T _{LEAD}	Maximum Soldering Temperature (at leads, 10 sec)	260	°C

$(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Thermal Capabilities

Symbol	Description	Value	Units
θја	Thermal Resistance – Junction to Ambient ²	73	°C/W
PD	Maximum Power Dissipation at $T_A \le 25^{\circ}C$	1090	mW
ΔΡ _D /ΔΤ	Derating Factor Above T _A = 25°C	-13.7	mW/°C

Ordering Information

Part Number	Marking ³	Operating Temperature	Package		
KTS1662EUW-TR	KVXXYY	-40°C to +85°C	WLCSP-12		

Recommended Operating Range⁴

Description	Value
Input voltage range	2.5V to 40V
Output capacitance range	Up to 100µF

^{1.} Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. Functional operation at conditions other than the operating conditions specified is not implied. Only one Absolute Maximum rating should be applied at any one time.

^{2.} Junction to Ambient thermal resistance is highly dependent on PCB layout. Values are based on thermal properties of the device when soldered to an EV board.

^{3. &}quot;KVXXYY" is the device ID code, date code and assembly code.

^{4.} The device is not guaranteed to function outside of recommended operating condition.



Electrical Characteristics⁵

Unless	otherwise	noted,	the	Min	and	Max	specs	are	applied	over	the	full	operation	temperature	range (of
-40°C t	o +85°C, w	hile Ty	p valı	ues a	are s	pecifi	ed at re	oom	tempera	ture (25°C). V	′ıℕ = 5.0V,	l _{IN} ≤3A		

Symbol	Description	Conditions	Min	Тур	Max	Unit
INPUT Ope	ration	•		•		
Vin	Input operating range		2.5		40	V
lin	Input supply current	$V_{IN} = 5V, V_{IN} < V_{IN_OVLO}, \overline{EN} = GND$		85		μΑ
VIN_UVLO	Under voltage lockout threshold	V _{IN} rising		2.3		V
VUVLO_HYST	Under voltage lockout hysteresis			0.1		V
OVP						
	Internal over voltage trip level 1	V _{IN} rising, OVLO = GND		5.95		V
VIN_OVLO	Internal over voltage trip level 2	V _{IN} rising, OVLO = FLOAT		10.2		V
	Internal over voltage trip level 3	V_{IN} rising, OVLO = $30k\Omega - 80k\Omega$ to GND		13.5		V
VIN_OVLO_HYS	OVLO Hysteresis	V _{IN} falling		0.10		V
	OVLO preset threshold range		1.17	1.20	1.23	V
VOVLO_TH	Adjustable OVLO threshold range		4		28	V
Vovlo_sel	External OVLO select threshold		0.2		0.3	V
R _{DS(ON)}	Switch On-Resistance	V _{IN} = 5V, I _{IN} = 1.0A, T _A = +25°C		26		mΩ
Iovlo	OVLO input leakage current	Vovlo = Vovlo_th	-120		120	nA
EN, VDET	•	•		•		
V _{EN_H}	EN logic high threshold		1.4			V
VEN_L	EN logic low threshold				0.4	V
RDET	VDET Switch On-resistance			25		Ω
V _{DET_OUT}	VDET clamp voltage	$V_{IN} = 20V, V_{EN} = 0V$	4.5	5.0	5.5	V
Vdet_lim	VDET current limit			30		mA
TIMING – F	igure 1	•		•		
tdeb	Debounce time	Time from 2.5V < V_{IN} < V_{IN_OVLO} to $V_{OUT} = 10\%$ of V_{IN}		18		ms
t _{ON}	Switch turn-on time	$V_{\text{IN}} = 5V, R_{\text{L}} = 100\Omega, C_{\text{LOAD}} = 100\mu F$ Vout from 10% V _{IN} to 90% V _{IN}		2		ms
toff	Switch turn-off time	$V_{IN} > V_{IN_OVLO}$ to V_{OUT} stop rising		100		ns
ESD PROT	ECTION			_		_
V _{ESD}	ESD Protection	Human Body Model(HBM) Model = 2		±2.0		kV
Thermal Sh	utdown		1	1		
Тенры	Shutdown Temperature			145		°C
י איטחטיי	Shutdown Temperature Hysteresis			20		°C

^{5.} KTS1662 is guaranteed to meet performance specifications over the -40°C to +85°C operating temperature range by design, characterization and correlation with statistical process controls.





^{*} NOTE: WAVEFORMS ARE NOT TO SCALE

Figure 1. Timing Diagram



Typical Characteristics

 $V_{IN} = 5V$, $C_{IN} = 0.1\mu$ F, $C_{OUT} = 1\mu$ F, OVLO pin = FLOAT, $\overline{EN} = GND$, Temp = 25°C unless otherwise specified.



Normalized RDS_ON vs Temperature



Normalized Fixed OVLO vs. Temperature (OVLO pin GND)



Normalized RDS_ON vs. Output Current



Normalized Debounce Time vs. Temperature



Normalized Adjustable OVLO vs. Temperature





Typical Characteristics



 $V_{IN} = 5V$, $C_{IN} = 0.1\mu$ F, $C_{OUT} = 1\mu$ F, OVLO pin = FLOAT, $\overline{EN} = GND$, Temp = 25°C unless otherwise specified.



KTS1662

Functional Block Diagram



Functional Description

The KTS1662 is inserted between the power supply or charger source and the load to be protected. The KTS1662 consists of a slew-rate controlled, low resistance OVP switch, under-voltage lockout protection (UVLO), overvoltage monitor and protection (OVLO) and a VBUS detect function (VDET).

The KTS1662 overvoltage protection device features a low on-resistance (R_{DSON}) internal FET and protects lowvoltage systems against voltage faults up to +40V. If the input voltage exceeds the overvoltage threshold, the internal FET is turned off to prevent damage to upstream components. The 18ms debounce time (18ms typ.) built into the device prevents false turn on of the internal FET during startup.

In normal operation, the OVP switch acts as a slew-rate controlled load switch, connecting and disconnecting the power supply from IN to OUT. A low resistance N-Channel MOSFET is used to minimize the voltage drop between the voltage source and the load and to reduce power dissipation.

When the voltage at the input exceeds the programmed overvoltage trip point, the device immediately turns off the internal switch disconnecting the load from the abnormal voltage, preventing damage to downstream components.

The VBUS detection function (VDET pin), provides a "clamped" output voltage whenever a voltage appears on VBUS (IN), and the power switch is enabled, even if the power switch is off due to an overvoltage condition.

In the event that the power dissipation causes the chip temperature to exceed its maximum temperature, the KTS1662 will switch off protecting the device. Once the chip temperature has cooled to below the hysteresis temperature, KTS1662 will re-initiate. Should the over-temperature condition persist, then KTS1662 will continue to thermally cycle on and off, until the input power is removed.



USB ON-The-Go (OTG) Operation

When used in an OTG application the KTS1662 can provide power from OUT to IN. Initially, the OTG voltage applied at OUT will forward bias the power switch bulk diode and present a voltage drop of approximately 0.7V between OUT and IN. The maximum current in this mode is limited by the thermal performance of the device and at an ambient temperature of 25°C, the maximum current is:

This is purely a transitionary condition as once the voltage at IN exceeds the UVLO voltage of 2.3V and the debounce time of 18ms has elapsed, the main power switch will turn fully ON, significantly reducing the voltage drop from OUT to IN.

N.B. In OTG mode, the OTG voltage will also appear at VDET output.

UVLO (Under Voltage Lockout)

The device has a built-in under voltage lockout (UVLO) circuit. When V_{IN} is rising, the output remains disconnected from the input until V_{IN} voltage is above 2.3V (typical). This circuit has a 100mV hysteresis to provide noise immunity to transient conditions.

OVLO (Over Voltage Lockout)

The KTS1662 adjustable version has a 1.2V (typ) overvoltage trip threshold on the OVLO pin. With a resistor divider on OVLO pin from IN to GND, the overvoltage protection point of IN can be adjusted between 4V and 28V. For correct operation, OVLO should be > 0.25V within 8ms after power up.

Fixed OVP products are available with an internal resistor divider providing 5.95V(typ), 10.2V(typ), or 13.5V(typ) OVLO threshold trip voltage. To select the internal Fixed OVP, the OVLO pin should be connected to GND (5.95V), allowed to FLOAT (10.2V) or connected to GND via a $30k\Omega$ to $80k\Omega$ resistor (13.5V).

Internal MOSFET Switch

The KTS1662 incorporates an internal MOSFET with a $26m\Omega$ (typ) $R_{DS(ON)}$. The MOSFET gate is driven by an integrated charge pump which generates the necessary voltage above IN.

Protected Bus Voltage

The KTS1662 passes a protected IN voltage through to VDET. The VDET pin can provide up to 3mA of DC current. VDET contains an internal 5.0V clamp to protect devices connected to VDET, while still allowing the devices to operate from the VDET voltage. The voltage at VDET is not present while the KTS1662 is in thermal shutdown or IN is lower than the input operating range.

Thermal Protection

The internal FET turns off when the junction temperature exceeds +145°C (typ). The device exits thermal shutdown after the junction temperature cools down by 20°C (typ).





Application Information

Input Capacitor

A 0.1µF or larger ceramic capacitor is recommended for CIN. The capacitor should be located close to the device IN pin. Ceramic capacitors are recommended for CIN. Select capacitors with a voltage rating at least 5V higher than the maximum possible voltage during surge. 50V rated capacitors are ideal for most applications.

Output Capacitor

A small ceramic capacitor of approximately 1µF is recommended at the output. If desired, COUT may be increased to accommodate any load transient condition.

External OVLO Adjustment

If OVLO is connected to ground, allowed to float or connected to ground via a resistor between the value of $30k\Omega$ to $80k\Omega$, the internal OVLO comparator uses the internally set OVLO value.

The adjustable threshold uses a 1.20V (typical) overvoltage trip threshold on the OVLO pin. With a resistor

divider on the OVLO pin from IN to GND, the overvoltage protection point of IN can be adjusted between 4V

and 28V. Once the OVLO pin voltage exceeds the OVLO select voltage, VovLo_SELECT (0.25V typical), the

comparator reads the OVLO pin voltage (a fraction of IN) set by the external resistor divider (R1, R2).

R1 = 1M Ω is a good starting value for minimum current consumption. Since V_{IN_OVLO}, V_{OVLO_THRESH}, and R1 are known, R2 can be calculated from the following formula:

 $V_{IN_OVLO} = V_{OVLO_TH} x (1+R1/R2) = 1.20V x (1+R1/R2)$

This external resistor-divider is completely independent from the internal resistor-divider.



KTS1662

Packaging Information

WLCSP34-12, 1.94mm x 1.28mm x 0.62mm Package



Recommended Footprint

(NSMD Pad Type)



* Dimensions are in millimeters.

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